# BS170G

# Small Signal MOSFET 500 mA, 60 Volts

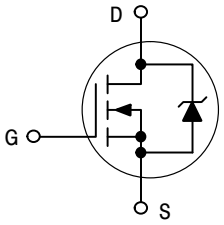
## N–Channel TO–92 (TO–226)

**ON Semiconductor®**

**http://onsemi.com**

**500 mA, 60 Volts**
**$R_{DS(on)}$ = 5.0 Ω**

**N–Channel**




### Features

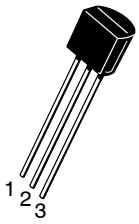
- This is a Pb–Free Device*

### MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|---|---|---|
| Drain – Source Voltage | $V_{DS}$ | 60 | Vdc |
| Gate–Source Voltage<br>– Continuous<br>– Non–repetitive ($t_p \le 50$ μs) | <br>$V_{GS}$<br>$V_{GSM}$ | <br>±20<br>±40 | <br>Vdc<br>Vpk |
| Drain Current (Note) | $I_D$ | 0.5 | Adc |
| Total Device Dissipation @ $T_A$ = 25°C | $P_D$ | 350 | mW |
| Operating and Storage Junction Temperature Range | $T_J$, $T_{stg}$ | –55 to +150 | °C |

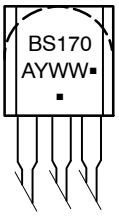
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

NOTE: The Power Dissipation of the package may result in a lower continuous drain current.




**TO–92 (TO–226)**
**CASE 29**
**STYLE 30**

### MARKING DIAGRAM & PIN ASSIGNMENT




1 Drain 2 Gate 3 Source

A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb–Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**ELECTRICAL CHARACTERISTICS** ($T_A$ = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|---|---|---|---|---|
| **OFF CHARACTERISTICS** | | | | | |
| Gate Reverse Current ($V_{GS}$ = 15 Vdc, $V_{DS}$ = 0) | $I_{GSS}$ | – | 0.01 | 10 | nAdc |
| Drain–Source Breakdown Voltage ($V_{GS}$ = 0, $I_D$ = 100 μAdc) | $V_{(BR)DSS}$ | 60 | 90 | – | Vdc |
| **ON CHARACTERISTICS** (Note 1) | | | | | |
| Gate Threshold Voltage ($V_{DS}$ = $V_{GS}$, $I_D$ = 1.0 mAdc) | $V_{GS(Th)}$ | 0.8 | 2.0 | 3.0 | Vdc |
| Static Drain–Source On Resistance ($V_{GS}$ = 10 Vdc, $I_D$ = 200 mAdc) | $r_{DS(on)}$ | – | 1.8 | 5.0 | Ω |
| Drain Cutoff Current ($V_{DS}$ = 25 Vdc, $V_{GS}$ = 0 Vdc) | $I_{D(off)}$ | – | – | 0.5 | μA |
| Forward Transconductance ($V_{DS}$ = 10 Vdc, $I_D$ = 250 mAdc) | $g_{fs}$ | – | 200 | – | mmhos |
| **SMALL–SIGNAL CHARACTERISTICS** | | | | | |
| Input Capacitance ($V_{DS}$ = 10 Vdc, $V_{GS}$ = 0, f = 1.0 MHz) | $C_{iss}$ | – | – | 60 | pF |
| **SWITCHING CHARACTERISTICS** | | | | | |
| Turn–On Time ($I_D$ = 0.2 Adc) See Figure 1 | $t_{on}$ | – | 4.0 | 10 | ns |
| Turn–Off Time ($I_D$ = 0.2 Adc) See Figure 1 | $t_{off}$ | – | 4.0 | 10 | ns |

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

## ORDERING INFORMATION

| Device | Package | Shipping† |
|---|---|---|
| BS170G | TO–92 (TO–226) (Pb–Free) | 1000 Unit/Tube |
| BS170RLRAG | TO–92 (TO–226) (Pb–Free) | 2000 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## RESISTIVE SWITCHING

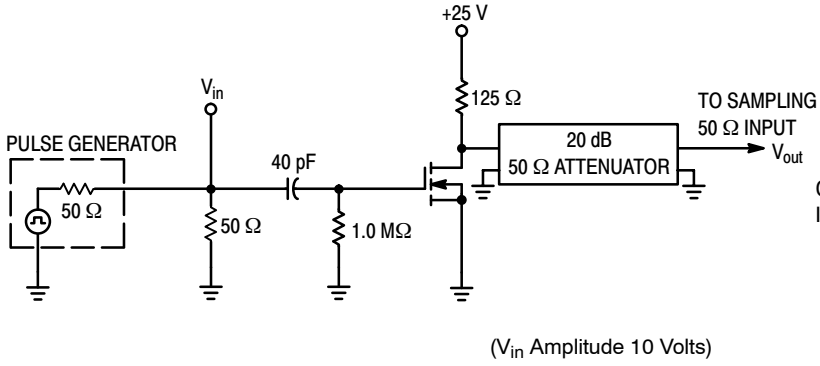



**Figure 1. Switching Test Circuit**

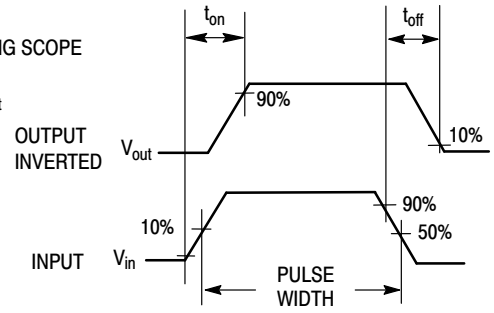



**Figure 2. Switching Waveforms**

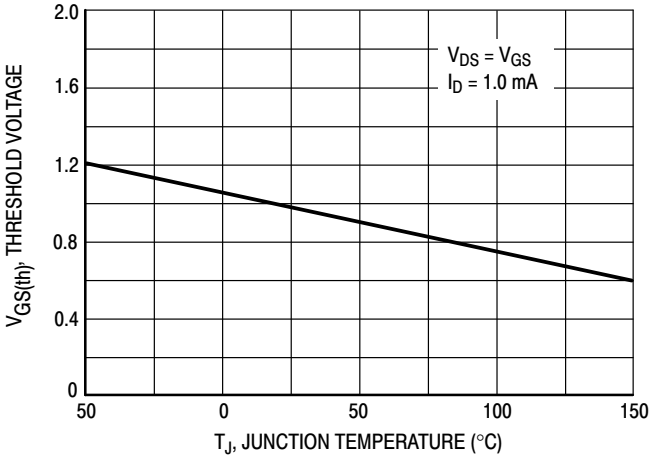



**Figure 3. $V_{GS(th)}$ Normalized versus Temperature**

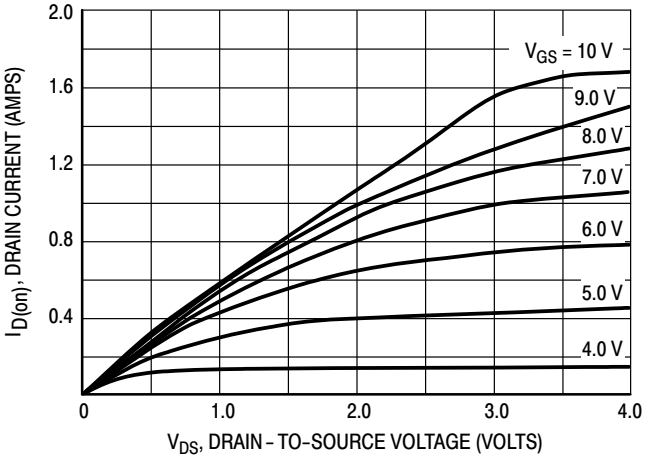



**Figure 4. On–Region Characteristics**

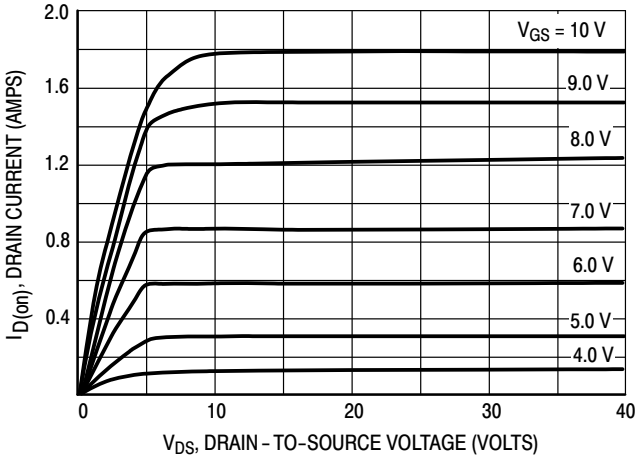



**Figure 5. Output Characteristics**

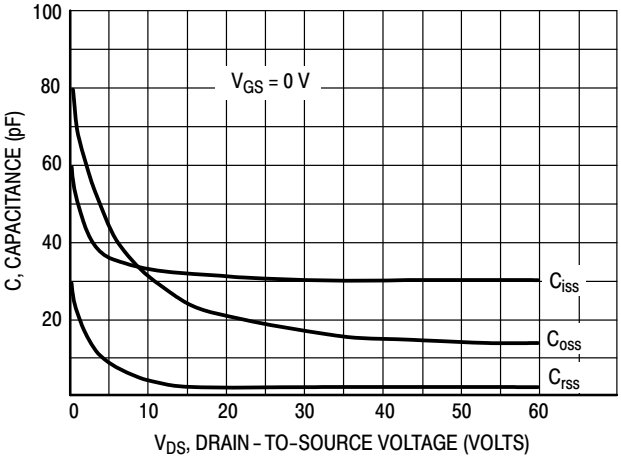
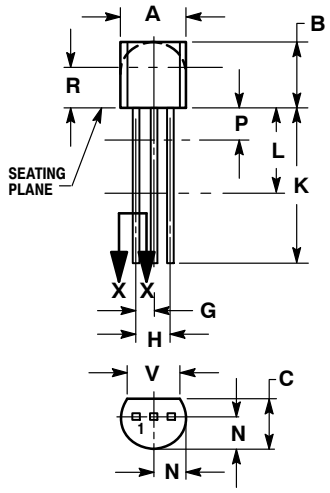


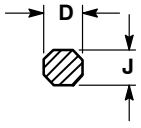

**Figure 6. Capacitance versus Drain–To–Source Voltage**

## PACKAGE DIMENSIONS

**TO−92 (TO−226)**
CASE 29−11
ISSUE AM



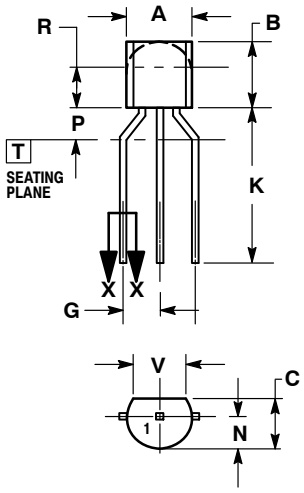

STRAIGHT LEAD
BULK PACK



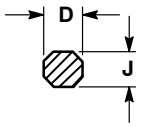

SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIMETERS | |
|---|---|---|---|---|
| DIM | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.115 | --- | 2.93 | --- |
| V | 0.135 | --- | 3.43 | --- |




BENT LEAD
TAPE & REEL
AMMO PACK




SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | MILLIMETERS | |
|---|---|---|
| DIM | MIN | MAX |
| A | 4.45 | 5.20 |
| B | 4.32 | 5.33 |
| C | 3.18 | 4.19 |
| D | 0.40 | 0.54 |
| G | 2.40 | 2.80 |
| J | 0.39 | 0.50 |
| K | 12.70 | --- |
| N | 2.04 | 2.66 |
| P | 1.50 | 4.00 |
| R | 2.93 | --- |
| V | 3.43 | --- |

STYLE 30:
PIN 1. DRAIN
2. GATE
3. SOURCE



## PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT**:
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**BS170/D**